

McKelvey School of Engineering

Spring Semester 2023

CSE463M-563M: Digital Integrated Circuit Design and Architecture

Homework #1

CSE 463M and CSE 563M students:

1) Solve problems (10 points each)

3.1, 3.2, 3.3, 3.6, 3.10, 3.12.

from Chapter 3 from the textbook. Please show all your work and be neat and circle your answers.

2) Cadence exercise (20 points):

Repeat Transistor I-V characteristics exercise from the Cadence wiki. Print out and submit

Transistor schematics and I-V graph just like it is done in the Cadence wiki. To access

Cadence you need to login to a Linux Machine at

<https://linuxlab.engr.wustl.edu>

Once you login to the Linux Machine start running Cadence exercise.

CSE 563M students only:

**In addition to the problem set above, please solve the following problem from the textbook:
3.9 (10 points).**

3.1

+ We know the following:

$$t_{ox} = 1.6 \text{ nm} = 1.6 \cdot 10^{-7} \text{ cm}$$

$$\Phi_{GC} = -1.04 \text{ V}$$

$$N_A = 2.8 \cdot 10^{18} \text{ cm}^{-3}$$

$$Q_{ox} = q \cdot 4 \cdot 10^{10} \text{ C/cm}^2 = 1.6 \cdot 10^{-19} \cdot 4 \cdot 10^{10} \text{ C/cm}^2 = 6.4 \cdot 10^{-9} \text{ C/cm}^2$$

$$\varepsilon_{ox} = 3.97 \varepsilon_0 = 3.97 \cdot 8.85 \cdot 10^{-14} \text{ F/cm} \quad (1 \text{ Farad} = 1 \frac{\text{C}}{\text{V}})$$

$$\varepsilon_{si} = 11.7 \varepsilon_0 = 11.7 \cdot 8.85 \cdot 10^{-14} \frac{\text{F}}{\text{cm}} (1 \text{ Farad} = 1 \frac{\text{C}}{\text{V}})$$

$$n_i = 1.45 \cdot 10^{10} \text{ cm}^{-3}$$

$$k = 1.38 \cdot 10^{-23} \text{ J/K}$$

$$q = 1.6 \cdot 10^{-19} \text{ C}$$

+ To get the threshold voltage, solve the equation below:

$$V_{T0} = \Phi_{GC} - 2\phi_F(\text{sub}) - \frac{Q_{B0}}{C_{ox}} - \frac{Q_{ox}}{C_{ox}}$$

+ First, $\phi_F(\text{sub})$:

$$\phi_F(\text{sub}) = \frac{kT}{q} \ln\left(\frac{n_i}{N_A}\right)$$

$$\frac{kT}{q} = \frac{1.38 \cdot 10^{-23} \text{ J/K} \cdot 300 \text{ K}}{1.6 \cdot 10^{-19} \text{ C}} = 0.026 \text{ V}$$

$$\ln\left(\frac{n_i}{N_A}\right) = \ln\left(\frac{1.45 \cdot 10^{10} \text{ cm}^{-3}}{2.8 \cdot 10^{18} \text{ cm}^{-3}}\right) = -19$$

$$\phi_F(\text{sub}) = \frac{kT}{q} \ln\left(\frac{n_i}{N_A}\right) = 0.026 \text{ V} \cdot -19 = -0.496 \text{ V}$$

+ Second, Q_{B0} :

$$Q_{B0} = -\sqrt{2 \cdot q \cdot N_A \cdot \varepsilon_{si} \cdot |-2\phi_F|}$$

$$= -\sqrt{2 \cdot (1.6 \cdot 10^{-19} \text{ C}) \cdot (2.8 \cdot 10^{18} \text{ cm}^{-3}) \cdot (11.7 \cdot 8.85 \cdot 10^{-14} \text{ F/cm}) \cdot |-2(-0.496 \text{ V})|}$$

$$= -9.593 \cdot 10^{-7} \text{ C/cm}^2$$

+ Third, C_{ox} :

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{3.97 \cdot 8.85 \cdot 10^{-14} \text{ F/cm}}{1.6 \cdot 10^{-7} \text{ cm}} = 2.195 \cdot 10^{-6} \text{ F/cm}^2$$

+ Finally, plug in all values above into equation:

$$\begin{aligned} V_{T0} &= \Phi_{GC} - 2\phi_F(sub) - \frac{Q_{B0}}{C_{ox}} - \frac{Q_{ox}}{C_{ox}} \\ &= -1.04 - 2(-0.496) - \frac{-9.593 \cdot 10^{-7}}{2.195 \cdot 10^{-6}} - \frac{6.4 \cdot 10^{-9}}{2.195 \cdot 10^{-6}} \\ &= 0.386 \text{ V} \end{aligned}$$

3.1.b.

+ The amount of channel implant:

$$\begin{aligned} \Delta V &= 0.6 - V_{T0} = 0.6 - 0.386 = 0.214 = \frac{qN_1}{C_{ox}} \\ N_1 &= \frac{\Delta V \cdot C_{ox}}{q} = \frac{0.214 \cdot 2.195 \cdot 10^{-6}}{1.6 \cdot 10^{-19}} = 2.953 \cdot 10^{12} \text{ cm}^{-2} \end{aligned}$$

+ The type is p-type since threshold voltage should be increased.

3.2

+ Constant values:

$$\epsilon_{si} = 11.7\epsilon_0 = 11.7 \cdot 8.85 \cdot 10^{-14} \frac{\text{F}}{\text{cm}} \quad (1 \text{ Farad} = 1 \frac{\text{C}}{\text{V}})$$

$$n_i = 1.45 \cdot 10^{10} \text{ cm}^{-3}$$

$$q = 1.6 \cdot 10^{-19} \text{ C}$$

+ The expression for the junction capacitance:

$$C_j(V) = A \sqrt{\frac{\epsilon_{si} \cdot q}{2} \left(\frac{N_A \cdot N_D}{N_A + N_D} \right)} \cdot \frac{1}{\sqrt{\phi_0 - V}}$$

+ for ϕ_0 :

$$\phi_0 = \frac{kT}{q} \ln \left(\frac{N_A \cdot N_D}{n_i^2} \right) = 0.026 \ln \left(\frac{2 \cdot 10^{20} \cdot 2 \cdot 10^{20}}{(1.45 \cdot 10^{10})^2} \right) = 1.214$$

+ for A :

$$A = 0.2 \cdot 0.4 + 2(0.2 \cdot 0.032) + 2(0.4 \cdot 0.032) = 1.184 \cdot 10^{-9}$$

+ Plug-in values:

$$C_j(V) = 1.184 \cdot 10^{-9} \sqrt{\frac{11.7 \cdot 8.85 \cdot 10^{-14} \cdot 1.6 \cdot 10^{-19} \left(\frac{4 \cdot 10^{40}}{4 \cdot 10^{20}} \right)}{2}} \cdot \frac{1}{\sqrt{1.214 + 1.2}} = 2.193 \cdot 10^{-15}$$

3.3.

They are not identical.

The electric channel length and the mask channel length have a relationship below:

$$L = L_M - 2L_D, \text{ where } L_D \text{ is the lateral diffusion length.}$$

3.6

+ we know the following:

$$N_D = 2 \cdot 10^{20} \text{ cm}^{-3}$$

$$N_A = 2 \cdot 10^{20} \text{ cm}^{-3}$$

$$X_j = 32 \text{ nm}$$

$$L_D = 10 \text{ nm}$$

$$t_{ox} = 1.6 \text{ nm}$$

$$V_{T0} = 0.53 \text{ V}$$

$$\text{Channel stop doping} = 16.0 \text{ X (p type substrate doping)}$$

$$\epsilon_{si} = 11.7\epsilon_0 = 11.7 \cdot 8.85 \cdot 10^{-14} \frac{\text{F}}{\text{cm}} \left(1 \text{ Farad} = 1 \frac{\text{C}}{\text{V}} \right)$$

$$q = 1.6 \cdot 10^{-19} \text{ C}$$

+ Drain capacitance equation:

$$C_{drain} = A \cdot C_{j0} \cdot K_{eq} + P \cdot C_{jsw} K_{eq(sw)}$$

+ for ϕ_0 :

$$\phi_0 = \frac{kT}{q} \ln \left(\frac{N_A \cdot N_D}{n_i^2} \right) = 0.026 \ln \left(\frac{2 \cdot 10^{20} \cdot 2 \cdot 10^{20}}{(1.45 \cdot 10^{10})^2} \right) = 1.21$$

+ for ϕ_{0sw} :

$$\phi_{0sw} = \frac{kT}{q} \ln \left(\frac{N_{A(sw)} \cdot N_D}{n_i^2} \right) = 0.026 \ln \left(\frac{16 \cdot 2 \cdot 10^{20} \cdot 2 \cdot 10^{20}}{(1.45 \cdot 10^{10})^2} \right) = 1.28$$

+ for C_{j0}, C_{jsw} :

$$C_{j0} = \sqrt{\frac{\epsilon_{si} \cdot q}{2} \left(\frac{N_A \cdot N_D}{N_A + N_D} \right)} \cdot \frac{1}{\sqrt{\phi_0}}$$

$$= \sqrt{\frac{11.7 \cdot 8.85 \cdot 10^{-14} \cdot 1.6 \cdot 10^{-19}}{2} \left(\frac{4 \cdot 10^{40}}{4 \cdot 10^{20}} \right)} \cdot \frac{1}{\sqrt{1.21}} = 2.61 \cdot 10^{-6} \text{ F/cm}^2$$

$$C_{j0sw} = \sqrt{\frac{\epsilon_{si} \cdot q}{2} \left(\frac{N_{A(sw)} \cdot N_D}{N_A + N_D} \right)} \cdot \frac{1}{\sqrt{\phi_{0sw}}}$$

$$= \sqrt{\frac{11.7 \cdot 8.85 \cdot 10^{-14} \cdot 1.6 \cdot 10^{-19}}{2} \left(\frac{4 \cdot 10^{40}}{4 \cdot 10^{20}} \right)} \cdot \frac{1}{\sqrt{1.28}} = 3.49 \cdot 10^{-6} \text{ F/cm}^2$$

$$C_{jsw} = X_j C_{j0sw} = 32 \cdot 10^{-9} \cdot 3.49 \cdot 10^{-6} = 0.11 \cdot 10^{-12} \text{ F/cm}$$

+ for A:

$$A = Y \cdot W = 6 \cdot 10 = 60 \mu\text{m}^2 = 60 \cdot 10^{-8} \text{ cm}^2$$

+ for P:

$$P = 2(Y + W) = 2(6 + 10) = 32 \mu\text{m} = 32 \cdot 10^{-4} \text{ cm}$$

+ for $K_{eq}, K_{eq(sw)}$:

$$K_{eq} = -\frac{2\sqrt{\phi_0}}{V_2 - V_1} (\sqrt{\phi_0 - V_2} - \sqrt{\phi_0 - V_1}) = 0.759$$

$$K_{eq(sw)} = -\frac{2\sqrt{\phi_{0sw}}}{V_2 - V_1} (\sqrt{\phi_{0sw} - V_2} - \sqrt{\phi_{0sw} - V_1}) = 0.768$$

+ Now, we can plugin values into Drain capacitance equation:

$$C_{drain} = A \cdot C_{j0} \cdot K_{eq} + P \cdot C_{jsw} \cdot K_{eq(sw)}$$

$$= 60 \cdot 10^{-8} \cdot 2.61 \cdot 10^{-6} \cdot 0.759 + 32 \cdot 10^{-4} \cdot 0.11 \cdot 10^{-12} \cdot 0.768$$

$$= 1.188 \text{ pF}$$

3.10

+ we know the following:

$$k' = 168 \mu A/V^2$$

$$V_{T0} = 0.48 V$$

$$\gamma = 0.52 V^{1/2}$$

$$|2\phi_F| = 1.01 V$$

+ Gate voltage is high and the V_x is expected to low. The load is in saturation and the driver is in linear region.

+ for V_T :

$$V_T = V_{T0} + \gamma(\sqrt{|-2\phi_F + V_{SB}|} - \sqrt{|-2\phi_F|})$$

$$V_T = 0.48 + 0.52(\sqrt{1.01 + V_x} - \sqrt{1.01})$$

+ From KCL:

$$I_D = I_{D,Driver} = I_{D,Load}$$

$$\frac{1}{2}k' \frac{W}{L} (1 - V_x - V_{T,L}(V_x))^2 = \frac{1}{2}k' \frac{W}{L} (2(1 - V_{T0})V_x - V_x^2)$$

$$(1 - V_x - V_{T,L}(V_x))^2 = (2(1 - 0.48)V_x - V_x^2)$$

$$(1 - V_x - V_{T,L}(V_x))^2 = 1.04V_x - V_x^2$$

+ To get V_x , plug in V_T into KCL equation:

$$(1 - V_x - V_{T,L}(V_x))^2 = 1.04V_x - V_x^2$$

$$(1 - V_x - (0.48 + 0.52(\sqrt{1.01 + V_x} - \sqrt{1.01})))^2 = 1.04V_x - V_x^2$$

$$V_x = 0.1357$$

+ To get I_D , plug in values into KCL equation:

$$I_D = I_{D,Driver} = I_{D,Load} = \frac{1}{2}k' \frac{W}{L} (1.04V_x - V_x^2) = \frac{1}{2} \cdot 168 \cdot 10 \cdot (1.04 \cdot 0.1357 - 0.1357^2) = 103.1 \mu A$$

3.12

+ For λ :

Choose row2 and row4 from the table.

$$\lambda = \frac{I_{D1} - I_{D2}}{V_{DS1}I_{D2} - V_{DS2}I_{D1}}$$

$$\lambda = \frac{59 - 60}{0.8 \cdot 60 - 1.0 \cdot 59} = 0.09 V^{-1}$$

+ For V_{T0} :

Choose row1 and row2 from the table.

$$\frac{I_{D1}}{I_{D2}} = \frac{(V_{GS1} - V_{T0})^2}{(V_{GS2} - V_{T0})^2}$$

$$V_{T0} = \frac{\sqrt{\frac{I_{D1}}{I_{D2}}} V_{GS2} - V_{GS1}}{\sqrt{\frac{I_{D1}}{I_{D2}}} - 1}$$

$$V_{T0} = \frac{\sqrt{\frac{8}{59}} \cdot 0.8 - 0.6}{\sqrt{\frac{8}{59}} - 1} = 0.48 \text{ V}$$

+ For k :

Choose row2 from the table.

$$I_{DSAT} = \frac{k}{2} (V_{GS} - V_T)^2 (1 + \lambda V_{DS})$$

$$59 = \frac{k}{2} (0.8 - 0.48)^2 (1 + 0.09 \cdot 0.8)$$

$$k = 1.08 \text{ mA/V}^2$$

$$2I_{DSAT} / ((V_{GS} - V_T)^2 (1 + \lambda V_{DS})) = k$$

+ For γ :

Choose row3 from the table.

$$37 = \frac{1075}{2} (0.8 - V_T (V_{BS} = -0.3))^2 (1 + 0.09 \cdot 0.8)$$

$$V_T (V_{BS} = -0.3) = 0.55 \text{ V}$$

$$V_T = V_{T0} + \gamma (\sqrt{|-2\phi_F + V_{SB}|} - \sqrt{|-2\phi_F|})$$

$$0.55 = 0.48 + \gamma (\sqrt{|1.1 + 0.3|} - \sqrt{|1.1|})$$

$$\gamma = 0.52 \text{ V}^{1/2}$$

3.9(For 563M)

+ We know the following:

$$t_{ox} = 1.6 \text{ nm} = 1.6 \cdot 10^{-7} \text{ cm}$$

$$\Phi_{GC} = -1.04 V$$

$$N_{D,sub} = 2 \cdot 10^{16} cm^{-3}$$

$$N_{D,poly} = 10^{20} cm^{-3}$$

$$Q_{ox} = q \cdot 4 \cdot 10^{10} C/cm^2 = 1.6 \cdot 10^{-19} \cdot 4 \cdot 10^{10} C/cm^2 = 6.4 \cdot 10^{-9} C/cm^2$$

$$\varepsilon_{ox} = 3.97 \varepsilon_0 = 3.97 \cdot 8.85 \cdot 10^{-14} F/cm \quad (1 \text{ Farad} = 1 \frac{C}{V})$$

$$\varepsilon_{si} = 11.7 \varepsilon_0 = 11.7 \cdot 8.85 \cdot 10^{-14} \frac{F}{cm} \quad (1 \text{ Farad} = 1 \frac{C}{V})$$

$$n_i = 1.45 \cdot 10^{10} cm^{-3}$$

$$k = 1.38 \cdot 10^{-23} J/K$$

$$q = 1.6 \cdot 10^{-19} C$$

$$\frac{kT}{q} = \frac{1.38 \cdot 10^{-23} J/K \cdot 300 K}{1.6 \cdot 10^{-19} C} = 0.026 V$$

+ To get the Φ_{GC} :

$$\Phi_{GC} = \phi_F(sub) - \phi_F(gate)$$

$$\phi_F(sub) = \frac{kT}{q} \ln \left(\frac{N_{D,sub}}{n_i} \right) = 0.026 \cdot \ln \left(\frac{2 \cdot 10^{16}}{1.45 \cdot 10^{10}} \right) = 0.367 V$$

$$\phi_F(gate) = \frac{kT}{q} \ln \left(\frac{N_{D,poly}}{n_i} \right) = 0.026 \cdot \ln \left(\frac{10^{20}}{1.45 \cdot 10^{10}} \right) = 0.589 V$$

$$\Phi_{GC} = 0.367 - 0.589 = -0.221 V$$

+ Second, Q_{B0} :

$$\begin{aligned} Q_{B0} &= \sqrt{2 \cdot q \cdot N_{D,sub} \cdot \varepsilon_{si} \cdot |2\phi_F|} \\ &= \sqrt{2 \cdot (1.6 \cdot 10^{-19} C) \cdot (2 \cdot 10^{16} cm^{-3}) \cdot (11.7 \cdot 8.85 \cdot 10^{-14} F/cm) \cdot |2 \cdot (0.374 V)|} \\ &= 6.974 \cdot 10^{-8} C/cm^2 \end{aligned}$$

+ Third, C_{ox} :

$$C_{ox} = \frac{\varepsilon_{ox}}{t_{ox}} = \frac{3.97 \cdot 8.85 \cdot 10^{-14} F/cm}{1.6 \cdot 10^{-7} cm} = 2.195 \cdot 10^{-6} F/cm^2$$

+ Finally, plug in all values above into equation:

$$V_{T0} = \Phi_{GC} - 2\phi_F(sub) - \frac{Q_{B0}}{C_{ox}} - \frac{Q_{ox}}{C_{ox}}$$

$$= -0.221 - 2(0.367) - \frac{6.974 \cdot 10^{-8}}{2.195 \cdot 10^{-6}} - \frac{6.4 \cdot 10^{-9}}{2.195 \cdot 10^{-6}}$$

$$= -0.9896 \text{ V}$$